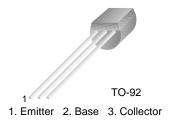


March 2009

MPSA77 **PNP Darlington Transistor**

- This device is designed for applications requiring extremely high current gain at currents to 800mA.
- Sourced from process 61.



Absolute Maximum Ratings * T_a =25°C unless otherwise noted

Symbol	Param	eter	Value	Units		
V _{CES}	Collector-Emitter Voltage		-60	V		
V _{CBO}	Collector-Base Voltage		-60	V		
V _{EBO}	Emitter-Base Voltage		-10	V		
I _C	Collector Current	- Continuous	-1.2	А		
T _J , T _{STG}	Operating and Storage Junction	n Temperature Range	-55 ~ +150	°C		

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

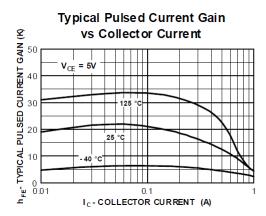
These ratings are based on a maximum junction temperature of 150 degrees C.
 These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

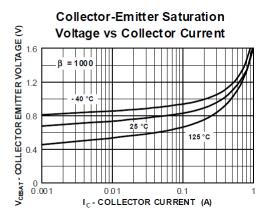
$\textbf{Electrical Characteristics} \ \, \textbf{T}_{a} \!\!=\!\! 25^{\circ} \textbf{C} \ \, \text{unless otherwise noted}$

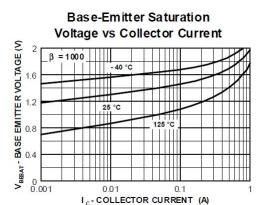
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characte	ristics				
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	$I_C = -100\mu A, I_B = 0$	-60		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = -30V, I_{E} = 0$		-100	nA
I _{EBO}	Emitter Cutoff Current	V _{EB} = -10V, I _C = 0		-100	nA
On Characte	ristics *				
h _{FE}	DC Current Gain	I _C = -10mA, V _{CE} = -5.0V I _C = -100mA, V _{CE} = -5.0V	10,000 10,000		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = -100 \text{mA}, I_B = -0.1 \text{mA}$		-1.5	V
V _{BE} (on)	Base-Emitter On Voltage	$I_C = -100 \text{mA}, V_{CE} = -5.0 \text{mA}$		-2.0	V
Small Signal	Characteristics *				
f _T	Current Gain Dandwidth Product	I _C = -10mA, V _{CE} = -5.0V f = 100MHz	100		MHz

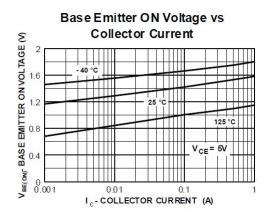
^{*} Pulse Test: Pulse Width $\leq 300 \mu s,$ Duty Cycle $\leq 2.0\%$

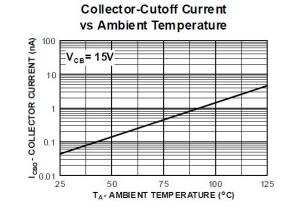
Typical Performance Characteristics

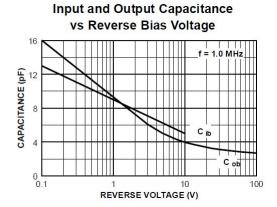






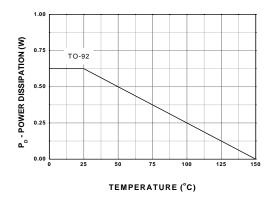




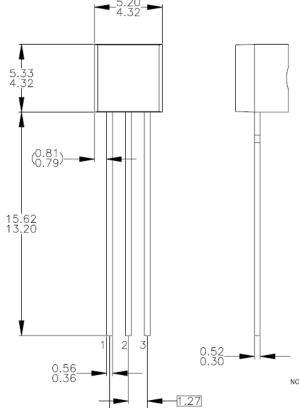


Typical Performance Characteristics (Continued)

Power Dissipation vs Ambient Temperature



Mechanical Dimensions (TO-92)



4.19 3.05 2 3

2.54

NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.

 B) ALL DIMENSIONS ARE IN MILLIMETERS.
 C) DRAWING CONFORMS TO ASME Y14.5M-1994.
 D) TO-92 (92,94,96,97,98) PIN CONFIGURATION:

≥ 92		94			96			97			98				
σ.	Р	F	М	Р	F	М	В	F	М	Р	F	М	Р	F	М
1	Ε	S	S	Ε	S	S	В	D	G	С	G	D	С	G	D
2	В	D	G	C	G	D	Ε	S	S	В	D	G	Ε	S	S
3	С	G	D	В	D	G	С	G	D	Ε	S	S	В	D	G

LEGEND:

P - BIPOLAR F - JFET M - DMOS EMITTERBASECOLLECTOR

- FOR PACKAGE 92, 94, 96, 97 AND 98: PIN CONFIGURATION DRAIN "D" AND SOURCE "S" ARE INTERCHANGEAGLE AT JFET "F" OPTION. DRAWING FILENAME: MKT-ZAO3DREV3. E)

Dimensions in Millimeters





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